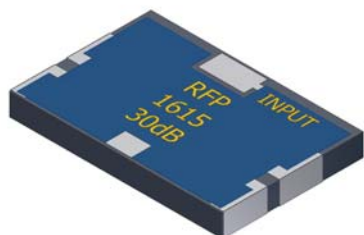


Chip Attenuator 100 Watts, 30 dB



Description

The 1615-30 is high performance Aluminum Nitride (AlN) chip attenuator intended as a cost competitive alternative to Beryllium Oxide (BeO). The attenuator is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The Attenuator is also RoHS compliant!

General Specifications

Resistive Element	Thick film
Substrate	AlN Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-55 to +200°C (see de rating chart)

Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet or exceed applicable portions of MIL-E-5400. **All dimensions in inches.**

Electrical Specifications

Attenuation Value:	30 dB	± 0.5 dB, DC - 960 MHz +0.5, -1 dB, 960 MHz - 2.3 GHz
Power:	100 Watts	
Frequency Range:	DC – 2.3 GHz	
Input Return Loss	19dB	

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

Features:

- RoHS Compliant
- 100 Watts
- DC – 2.3 GHz
- AlN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Outline Drawing

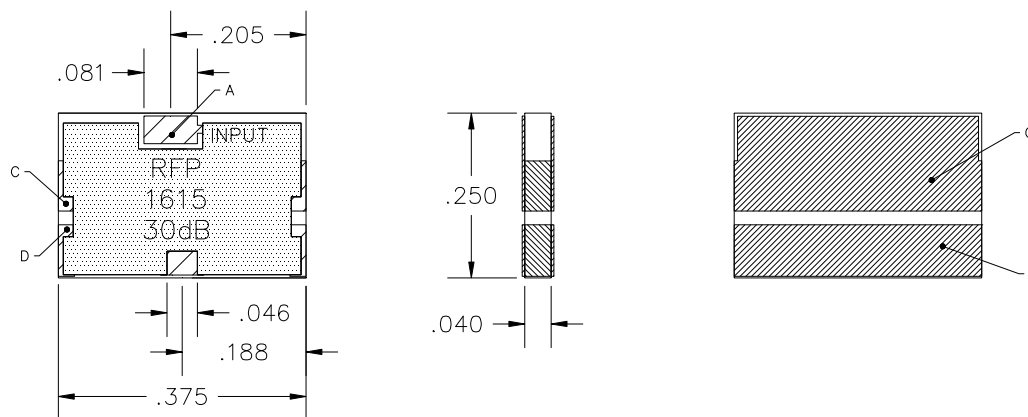


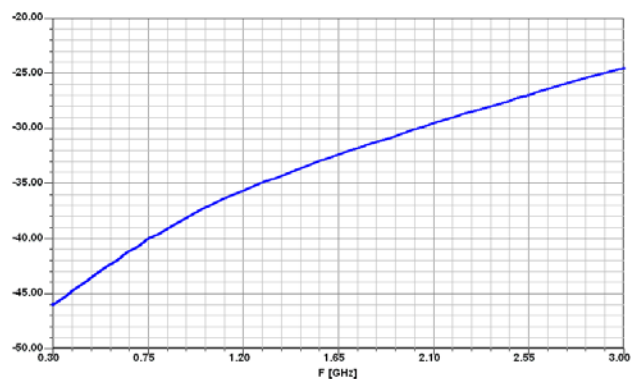
TABLE 1: RESISTOR VALUE CHART				
ATTENUATION	A – B	A – C	B – D	TOLERANCE
30 dB	790 Ω	53 Ω	53 Ω	$\pm 4\%$

UNLESS OTHERWISE SPECIFIED DIMENSIONS ARE IN INCHES.
TOLERANCES ON DECIMALS .XXX $\pm .010$

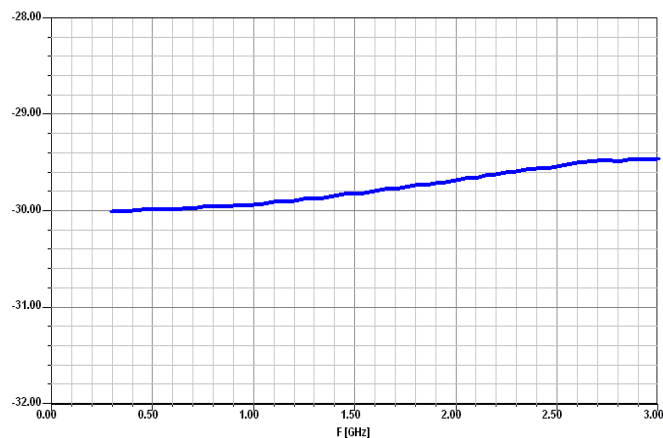
1615-30 pg.1 of 2

Typical Performance:

Return Loss

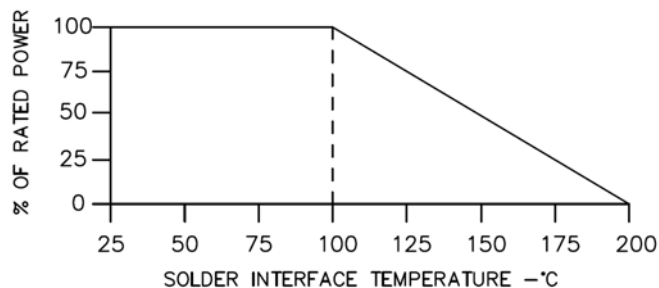


Attenuation



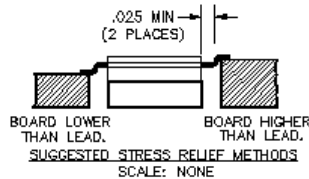
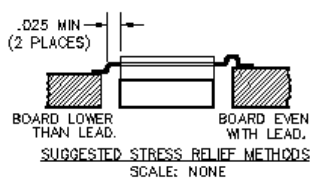
Power De-rating:

POWER DERATING



*Actual performance could be limited by the solder properties of the application

Mounting Procedure:



SUGGESTED MOUNTING PROCEDURES:

1. MAKE SURE THAT THE DEVICES ARE MOUNTED ON FLAT SURFACES TO OPTIMIZE THE HEAT TRANSFER.
2. RECOMMENDED FLATNESS UNDER THE DEVICE IS 0.002".
3. POSITION DEVICE ON MOUNTING SURFACE AND SOLDER IN PLACE USING AN APPROPRIATE SOLDER